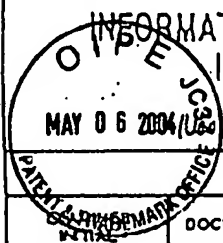


Form PTO-1449

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INFORMATION DISCLOSURE CITATION
IN AN APPLICATION.

MAY 06 2004 (Use several sheets if necessary)

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Applicant

Indrajit Manna et al.

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2826

U. S. PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	TITLE	CLASS	SUBCLASS	PUB. DATE IF APPROPRIATE
/KQ/	6610262	8/26/03	Peng et al.	423	197	3/4/02
	6605493	8/12/03	Yu	438	135	8/29/01
	6580184	6/17/03	Song	307	112	5/16/02
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	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/KQ/	US Patent App. Pub. US 2003/0016479 A1 to Song, Pub. Date 1/23/03, Filed 5/16/02, US Cl. 361/56.
/KQ/	S. Voldman et al., "Electrostatic Discharge (ESD) Protection in Silicon-on-Insulator (SOI) CMOS Technology with Aluminum and Copper Interconnects in Advanced Microprocessor Semiconductor Chips"; EOS/ESD Symposium 99-105, 2A.6.1 to 2A.6.11.
EXAMINER	/Kevin Quinto/
DATE CONSIDERED	03/12/2007

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